IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application.

1. (Currently Amended) A light emitting element comprising a plurality of layers interposed between a pair of electrodes opposed to each other,

wherein at least one of the plurality of layers is formed of a layer containing a light emitting material, and

wherein the layer containing the light emitting material is interposed between a layer containing an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property, and a layer containing an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property.

- 2. (Original) A display device comprises the light emitting element according to claim 1 in a pixel portion.
- 3. (Currently Amended) A light emitting element comprising a plurality of layers interposed between a pair of electrodes opposed to each other,

wherein at least one of the plurality of layers is formed of a layer containing a light emitting material, and

wherein the layer containing the light emitting material is interposed between a layer containing an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher

hole transporting property than an electron transporting property, and a layer containing an oxide semiconductor or metal oxide, a material having a higher electron transporting property than a hole transporting property and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property.

- 4. (Original) A display device comprises the light emitting element according to claim 3 in a pixel portion.
 - 5 (Currently Amended) A light emitting element comprising:

a pair of electrodes; and

first to third layers sequentially laminated between the pair of electrodes,

wherein the first layer contains an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material, and

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property.

- 6. (Currently Amended) A light emitting element according to claim 5, wherein the first layer comprises molybdenum oxide and 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.
- 7. (Original) A display device comprises the light emitting element according to claim 5 in a pixel portion.

8. (Currently Amended) A light emitting element comprising:

a pair of electrodes; and

first to third layers sequentially laminated between the pair of electrodes,

wherein the first layer contains an oxide semiconductor or metal-oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material, and

wherein the third layer contains an oxide semiconductor or metal oxide, a material having a higher electron transporting property than a hole transporting property, and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property.

- 9. (Currently Amended) A light emitting element according to claim 8, wherein the first layer comprises molybdenum oxide and 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.
- 10. (Original) A display device comprises the light emitting element according to claim 8 in a pixel portion.
 - 11. (Currently Amended) A light emitting element comprising:

a pair of electrodes; and

first to fourth layers sequentially laminated between the pair of electrodes,

wherein the first layer contains an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property, and

wherein the fourth layer contains an oxide semiconductor or metal oxide, a material having a higher electron transporting property than a hole transporting property, and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property.

- 12. (Currently Amended) A light emitting element according to claim 11, wherein the first layer comprises molybdenum oxide and 4,4(-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.
- 13. (Original) A display device comprises the light emitting element according to claim 11 in a pixel portion.
 - 14. (Currently Amended) A light emitting element comprising:

a pair of electrodes; and

first to fourth layers sequentially laminated between the pair of electrodes,

wherein the first layer contains an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property, and

wherein the fourth layer contains a material having a higher electron transporting property than a hole transporting property and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property.

15. (Currently Amended) A light emitting element according to claim 14, wherein the first layer comprises molybdenum oxide and 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

16. (Original) A display device comprises the light emitting element according to claim 14 in a pixel portion.

17 (Currently Amended). A light emitting element comprising:

a pair of electrodes; and

first to fourth layers sequentially laminated between the pair of electrodes,

wherein the first layer contains an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property, and

wherein the fourth layer contains an oxide semiconductor or metal oxide and a material having a higher hole transporting property than an electron transporting property.

18. (Original) A light emitting element according to Claim 17, wherein the first layer and the

fourth layer are formed using the same material.

19. (Currently Amended) A light emitting element according to claim 17, wherein the first layer comprises molybdenum oxide and 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

20. (Original) A display device comprises the light emitting element according to claim 17 in a pixel portion.

21-24. (Canceled)

25. (Currently Amended) A light emitting element comprising:

a pair of electrodes; and

first to fifth layers sequentially laminated between the pair of electrodes,

wherein the first layer contains an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property,

wherein the fourth layer contains an oxide semiconductor or metal oxide, a material having a higher electron transporting property than a hole transporting property, and a material which can donate an electron to the material having a higher electron transporting property than a hole transporting property, and

wherein the fifth layer contains an oxide semiconductor or metal oxide and a material having a higher hole transporting property than an electron transporting property.

26. (Original) A light emitting element according to Claim 25, wherein the first layer and the fifth layer are formed using the same material.

27. (Currently Amended) A light emitting element according to claim 25, wherein the first layer comprises molybdenum oxide and 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.

28. (Original) A display device comprises the light emitting element according to claim 25 in a pixel portion.

29. (Currently Amended) A light emitting element comprising:

a pair of electrodes; and

first to fifth layers sequentially laminated between the pair of electrodes,

wherein the first layer contains an oxide semiconductor or metal oxide molybdenum oxide and a material having a higher hole transporting property than an electron transporting property,

wherein the second layer contains a light emitting material,

wherein the third layer contains an oxide semiconductor or metal oxide and a material having a higher electron transporting property than a hole transporting property,

wherein the fourth layer contains a material having a higher electron transporting property than a hole transporting property and a material which can donate an electron to the material having a

higher electron transporting property than a hole transporting property, and

wherein the fifth layer contains an oxide semiconductor or metal oxide and a material having a higher hole transporting property than an electron transporting property.

- 30. (Original) A light emitting element according to Claim 29, wherein the first layer and the fifth layer are formed using the same material.
- 31. (Currently Amended) A light emitting element according to claim 29, wherein the first layer comprises molybdenum-oxide and 4,4'-bis[N-(1-naphthyl)-N-phenylamino]biphenyl.
- 32. (Original) A display device comprises the light emitting element according to claim 29 in a pixel portion.